

**FEATURES**

- 10-Bit Resolution
- Sampling Rate to 6 MSPS
- DNL =  $\pm 1$  LSB, INL =  $\pm 2$  LSB
- Internal S/H Function
- Single 5V Power Supply
- $V_{IN}$  DC Range: 0V to  $V_{DD}$
- $V_{REF}$  DC Range: 1V to  $V_{DD}$
- Low Power: 65mW
- Three-State Digital Outputs
- Latch-Up Free

**APPLICATIONS**

- Digital Color Copiers
- Digital Cellular Telephones
- Precision CCDs and Scanners
- Medical Scanners
- Ultrasonics
- Digital Radio

**BENEFITS**

- Simplified Analog Design
- Rugged
- Few External Components, no S/H Needed
- Reduced Board Space

**GENERAL DESCRIPTION**

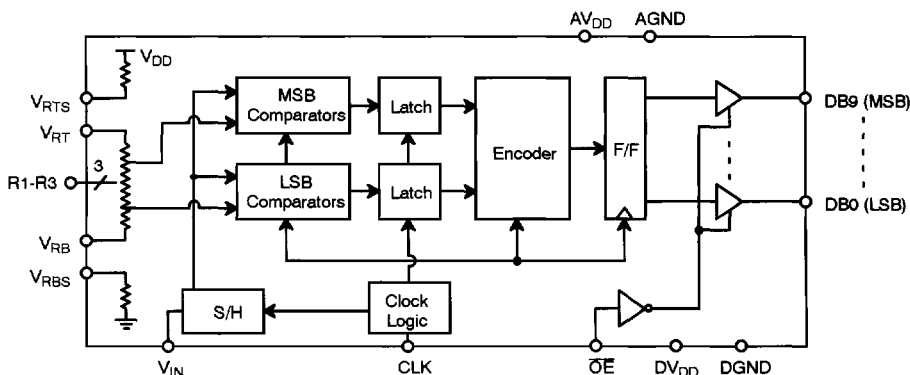
The XRD6406 is a 10-bit, 6 MSPS, Analog-to-Digital Converter for applications that require high speed and high accuracy. Designed using an advanced CMOS process, this part offers excellent performance, low power consumption and latch-up free operation.

The XRD6406 uses a subranging architecture to maintain low power consumption at high conversion rates. Our proprietary comparator design achieves a low analog input capacitance. The input circuitry of the XRD6406 includes an on-chip S/H function that allows this part to digitize analog input signals between AGND and  $AV_{DD}$ .

The designer can choose the internally generated reference voltages, or provide external reference voltages to the  $V_{RB}$  and  $V_{RT}$  pins. The internal reference generates 1.0V at  $V_{RB}$  and 4V at  $V_{RT}$ . Providing external reference voltages allows easy interface to any input signal range between GND and  $V_{DD}$ . This also allows the system to cancel zero scale and full scale errors. The Reference Ladder taps (R1 to R3) can be used to externally trim any INL errors.

This device operates from a single 5V supply. Power consumption from a 5V supply is typically 65mW at  $F_S=6$ MHz.

**SIMPLIFIED BLOCK DIAGRAM**

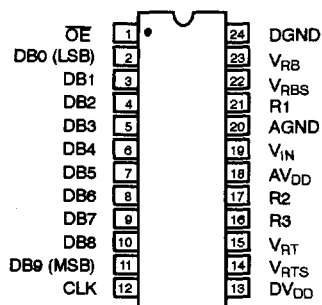


## ORDERING INFORMATION

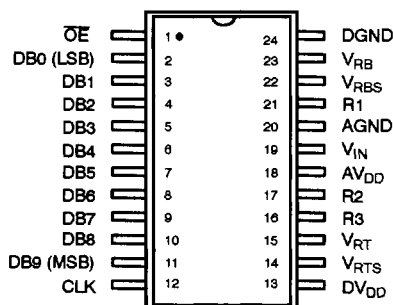
Package Type	Temperature Range	Part No.	DNL (LSB)	INL (LSB)
Plastic Dip	-40 to +85°C	XRD6406AIP	±1	±2
SOIC	-40 to +85°C	XRD6406AID	±1	±2

## PIN CONFIGURATIONS

See Packaging Section for Package Dimensions



24 Pin PDIP (0.300")



24 Pin SOIC (Jedec, 0.300")

## PIN OUT DEFINITIONS

PIN NO.	NAME	DESCRIPTION
1	OE	Output Enable
2	DB0	Data Output Bit 0 (LSB)
3	DB1	Data Output Bit 1
4	DB2	Data Output Bit 2
5	DB3	Data Output Bit 3
6	DB4	Data Output Bit 4
7	DB5	Data Output Bit 5
8	DB6	Data Output Bit 6
9	DB7	Data Output Bit 7
10	DB8	Data Output Bit 8
11	DB9	Data Output Bit 9 (MSB)
12	CLK	Clock Input

PIN NO.	NAME	DESCRIPTION
13	DV <sub>DD</sub>	Digital Power Supply
14	V <sub>RTS</sub>	Top Internal Reference
15	V <sub>RT</sub>	Top of Reference
16	R3	3/4 Reference Tap Point
17	R2	1/2 Reference Tap Point
18	AV <sub>DD</sub>	Analog Power Supply
19	V <sub>IN</sub>	Analog Input Voltage
20	AGND	Analog Ground
21	R1	1/4 Reference Tap Point
22	V <sub>RBS</sub>	Bottom Internal Reference
23	V <sub>RB</sub>	Bottom of Reference
24	DGND	Digital Ground

**ELECTRICAL CHARACTERISTICS TABLE**

 Unless Otherwise Specified:  $AV_{DD} = DV_{DD} = 5V$ ,  $FS = 6MHz$  (50% Duty Cycle),

 $V_{RT} = 4.0$ ,  $V_{RB} = 1.0$ ,  $T_A = 25^\circ C$ 

Parameter	Symbol	25°C			Units	Test Conditions/Comments
		Min	Typ	Max		
<b>KEY FEATURES</b>						
Resolution		10			Bits	
Maximum Sampling Rate	FS	6			MHz	
<b>ACCURACY (A Grade)<sup>1</sup></b>						
Differential Non-Linearity	DNL			±1	LSB	Best Fit Line (Max INL - Min INL)/2
Integral Non-Linearity	INL			±2	LSB	
Zero Scale Error	EZS		10		LSB	
Full Scale Error	EFS		6		LSB	
<b>REFERENCE VOLTAGES</b>						
Positive Ref. Voltage <sup>3</sup>	$V_{RT}$			$AV_{DD}$	V	$V_{REF} = V_{RT} - V_{RB}$
Negative Ref. Voltage <sup>3</sup>	$V_{RB}$	AGND			V	
Differential Ref. Voltage <sup>3</sup>	$V_{REF}$	1.0		$AV_{DD}$	V	
Ladder Resistance	$R_L$		1400		Ω	
Ladder Temp. Coefficient <sup>2</sup>	$R_{TCO}$		2000		ppm/°C	
Top Internal Reference	$V_{RTS}$		4		V	$V_{RT}$ connected to $V_{RTS}$ & $V_{RB}$ connected to $V_{RBS}$
Bottom Internal Reference	$V_{RBS}$		1		V	
<b>ANALOG INPUT<sup>2</sup></b>						
Input Bandwidth (-1 dB) <sup>4</sup>	BW		25		MHz	
Input Voltage Range	$V_{IN}$	$V_{RB}$		$V_{RT}$	V	
Input Capacitance Sample <sup>5</sup>	$C_{IN}$		25	40	pF	
Input Capacitance Convert <sup>5</sup>			7	12	pF	
Aperture Delay <sup>2</sup>	$t_{AP}$		25	30	ns	
Aperture Uncertainty <sup>2</sup> (Jitter)	$t_{AJ}$		50		ps	
<b>DIGITAL INPUTS</b>						
Logical "1" Voltage	$V_{IH}$	4			V	$V_{IN} = DGND$ to $DV_{DD}$
Logical "0" Voltage	$V_{IL}$			1	V	
DC Leakage Currents <sup>6</sup>	$I_{IN}$		5		μA	
CLK			5		μA	
$\overline{OE}$			5		μA	
Input Capacitance			5		pF	
Clock Timing (See Figure 1)						
Clock Period	1/FS		200		ns	
Rise & Fall Time <sup>7</sup>	$t_R, t_F$		5		ns	
"High" Pulse Width <sup>3</sup>	$t_{PWH}$		100		ns	
"Low" Pulse Width <sup>3</sup>	$t_{PWL}$		100		ns	
Duty Cycle <sup>3</sup>			50		%	
<b>DIGITAL OUTPUTS</b>						
Logical "1" Voltage	$V_{OH}$	4.5			V	$C_{OUT} = 15$ pF $I_{LOAD} = 4$ mA $I_{SINK} = 4$ mA $V_{OUT} = DGND$ to $DV_{DD}$
Logical "0" Voltage	$V_{OL}$			0.4	V	
3-state Leakage	$I_{OZ}$		10		μA	
Data Valid Delay <sup>2</sup>	$t_{DL}$		40	45	ns	
Data Enable Delay <sup>2</sup>	$t_{DEN}$		25	30	ns	
Data 3-state Delay <sup>2</sup>	$t_{DHZ}$		25	30	ns	

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## ELECTRICAL CHARACTERISTICS TABLE (CONT'D)

Description	Symbol	25°C			Units	Conditions
		Min	Typ	Max		
<b>POWER SUPPLIES</b>						
Operating Voltage (AV <sub>DD</sub> , DV <sub>DD</sub> ) <sup>8, 9</sup>	V <sub>DD</sub>	4.5	5	5.5	V	
Current (AV <sub>DD</sub> + DV <sub>DD</sub> )	I <sub>DD</sub>		13	17	mA	

### Notes:

- <sup>1</sup> *Tester measures code transitions by dithering the voltage of the analog input (V<sub>IN</sub>). The difference between the measured and the ideal code width (V<sub>REF</sub>/1024) is the DNL error (Figure 3.). The INL error is the maximum distance (in LSBs) from the best fit line to any transition voltage (Figure 4.). Accuracy is a function of the sampling rate (FS).*
- <sup>2</sup> *Guaranteed. Not tested.*
- <sup>3</sup> *Specified values guarantee functionality. Refer to other parameters for accuracy.*
- <sup>4</sup> *-1 dB bandwidth is a measure of performance of the A/D input stage (S/H + amplifier). Refer to other parameters for accuracy within the specified bandwidth.*
- <sup>5</sup> *See V<sub>IN</sub> equivalent circuit (Figure 8.). Switched capacitor analog input requires driver with low output resistance.*
- <sup>6</sup> *All inputs have diodes to DV<sub>DD</sub> and DGND. Input DC currents will not exceed specified limits for any input voltage between DGND and DV<sub>DD</sub>.*
- <sup>7</sup> *Condition to meet aperture delay specifications (t<sub>AP</sub>, t<sub>AJ</sub>). Actual rise/fall time can be less stringent with no loss of accuracy.*
- <sup>8</sup> *The AGND & DGND pins are connected through the silicon substrate. Connect together at the package and to the analog ground plane.*
- <sup>9</sup> *The AV<sub>DD</sub> & DV<sub>DD</sub> pins should be tied together at the package.*

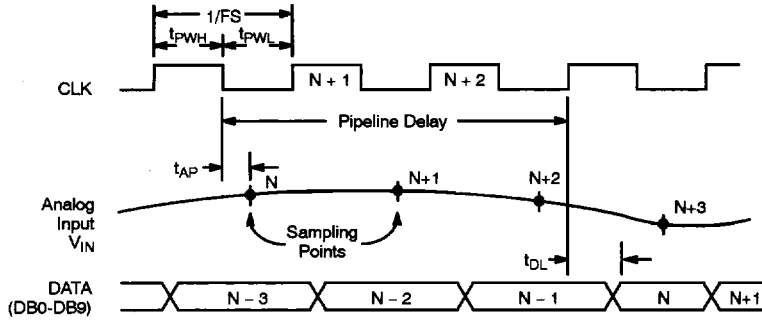
Specifications are subject to change without notice

## ABSOLUTE MAXIMUM RATINGS (TA = +25°C unless otherwise noted)<sup>1, 2, 3</sup>

AV <sub>DD</sub> to AGND .....	+7V	Storage Temperature .....	-65 to +150°C
V <sub>RT</sub> & V <sub>RB</sub> .....	V <sub>DD</sub> +0.5 to GND -0.5V	Package Power Dissipation Rating to 75°C	
V <sub>IN</sub> .....	V <sub>DD</sub> +0.5 to GND -0.5V	PDIP, SOIC .....	1000mW
All Inputs .....	V <sub>DD</sub> +0.5 to GND -0.5V	Derates above 75°C .....	14mW/°C
All Outputs .....	V <sub>DD</sub> +0.5 to GND -0.5V	Lead Temperature (Soldering 10 seconds) .....	+300°C

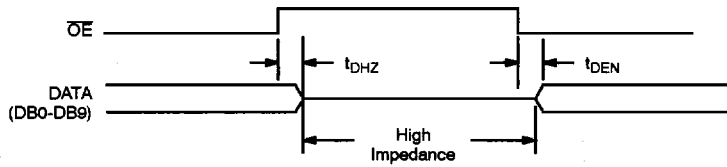
### Notes

- <sup>1</sup> *Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation at or above this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.*
- <sup>2</sup> *Any input pin which can see a value outside the absolute maximum ratings should be protected by Schottky diode clamps (HP5082-2835) from input pin to the supplies. All inputs have protection diodes which will protect the device from short transients outside the supplies of less than 100mA for less than 100µs.*
- <sup>3</sup> *V<sub>DD</sub> refers to AV<sub>DD</sub> and DV<sub>DD</sub>. GND refers to AGND and DGND.*



**Figure 1. XRD6406 Timing Diagram**

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**Figure 2. 3-State Timing Diagram**

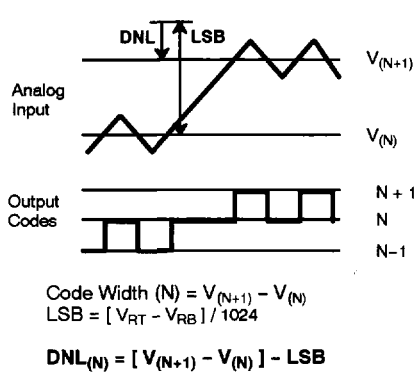


Figure 3. DNL Measurement

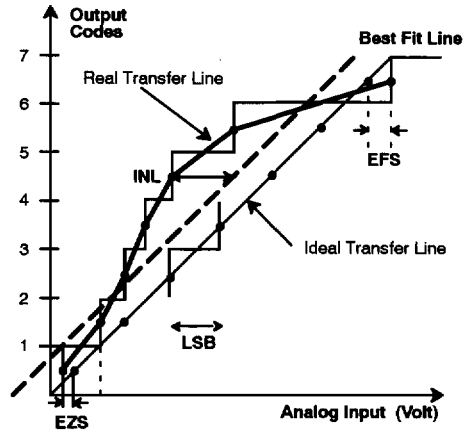


Figure 4. INL Error Calculation

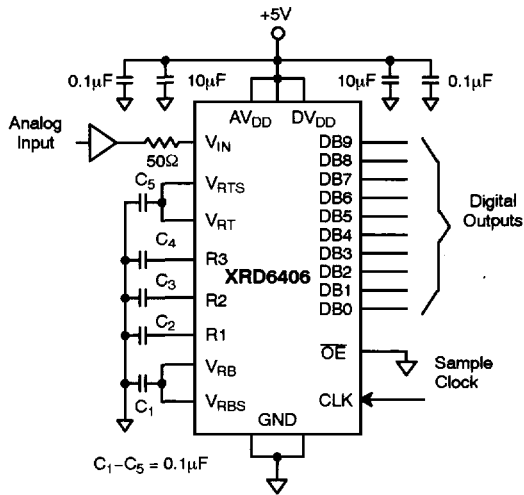


Figure 5. Typical Circuit Connections

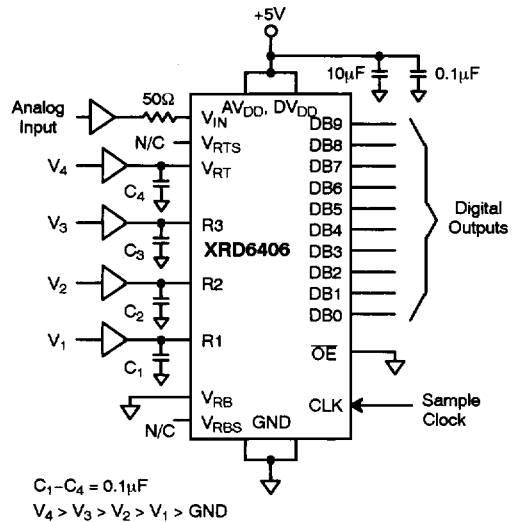


Figure 6. Creating a Piece Wise Linear Transfer Function

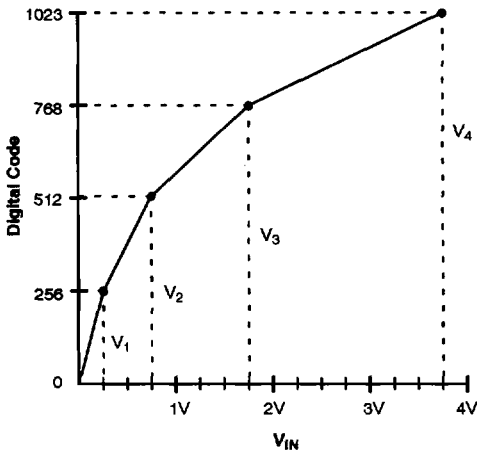


Figure 7. A Piece Wise Linear, Logarithmic Transfer Function

## APPLICATION NOTES

Signals should not exceed  $AV_{DD}$  or  $DV_{DD} + 0.5V$  or go below  $DGND$  or  $AGND - 0.5V$ . All pins have internal protection diodes that will protect them from short transients ( $< 100\mu s$ ) outside the supply range.

$AGND$  and  $DGND$  pins are connected internally through the P-substrate. DC voltage differences between these pins will cause undesirable internal substrate currents.

The power supply ( $AV_{DD}$ ) and reference voltage ( $V_{RT}$  &  $V_{RB}$ ) pins should be decoupled with  $0.1\mu F$  and  $10\mu F$  capacitors to  $AGND$ , placed as close to the chip as possible.

The digital outputs should not drive long wires or buses. The capacitive coupling and reflections will contribute noise to the conversion.

## V<sub>IN</sub> Analog Input

This part has a switched capacitor type input circuit. This means that the input impedance changes with the phase of the input clock.  $V_{IN}$  is sampled at the high to low clock transition. Figure 8. shows an equivalent input circuit.

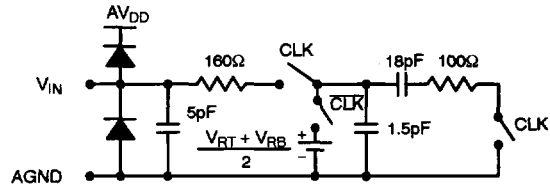


Figure 8. Equivalent Input Circuit

## RTS & RBS Internal Bias Resistors

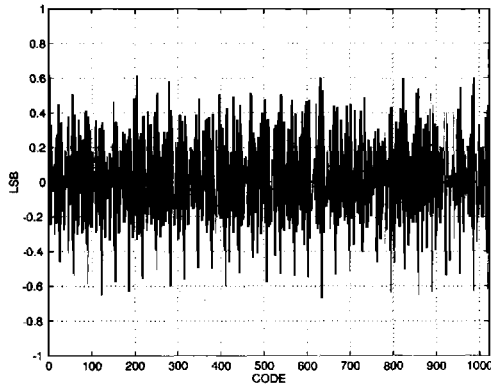
Two matched resistors are provided on the chip. These resistors can be used to generate on chip reference voltages. Each resistor has a value equal to 1/3 of the reference ladder resistor. By connecting  $RTS$  to  $V_{RT}$ , and connecting  $RBS$  to  $V_{RB}$ , the reference ladder will be biased to 1V at  $V_{RB}$  and 4V at  $V_{RT}$ .

If the internal reference pins  $V_{RTS}$  and/or  $V_{RBS}$  are not used they should be left unconnected.

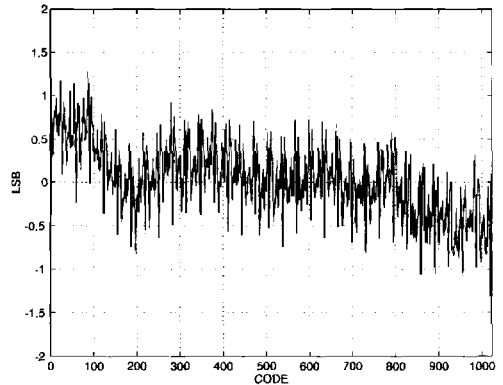
## R1 thru R3 Reference Ladder Taps

These taps connect to every quarter point along the reference ladder; R1 is 1/4th up from  $V_{RB}$ , R3 is 3/4ths up from  $V_{RB}$  (or 1/4th down from  $V_{RT}$ ). Normally these pins should have 0.1 microfarad capacitors to  $AGND$ ; this helps reduce the INL errors by stabilizing the reference ladder voltages. These taps can also be used to alter the transfer curve of the ADC. A four segment, piecewise linear, custom transfer curve can be designed by connecting voltage sources to these pins.

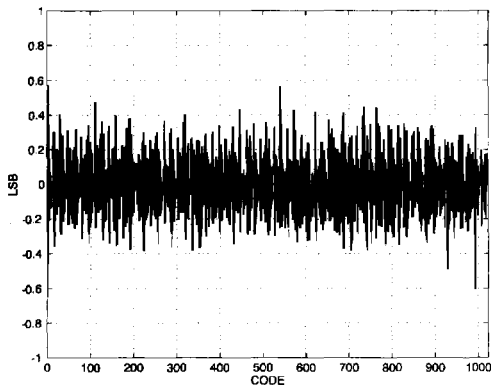
## PERFORMANCE CHARACTERISTICS



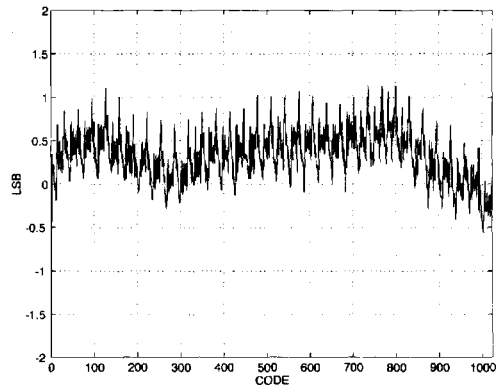
**Graph 1. XRD6406, DNL @ 5MSPS**  
 $DV_{DD} = 5V, AV_{DD} = 5V, V_{RT} = 4V, V_{RB} = 1V$



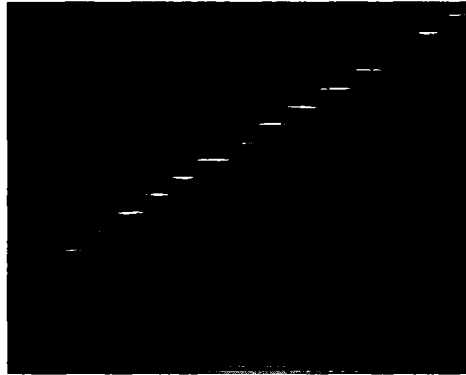
**Graph 2. XRD6406, INL @ 5MSPS**  
 $DV_{DD} = 5V, AV_{DD} = 5V, V_{RT} = 4V, V_{RB} = 1V$



**Graph 3. XRD6406, DNL @ 5MSPS**  
 $DV_{DD} = 3V, AV_{DD} = 5V, V_{RT} = 4.5V, V_{RB} = 0.5V$

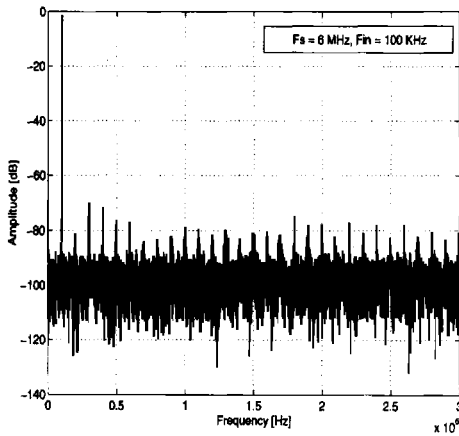


**Graph 4. XRD6406, INL @ 5MSPS**  
 $DV_{DD} = 3V, AV_{DD} = 5V, V_{RT} = 4.5V, V_{RB} = 0.5V$

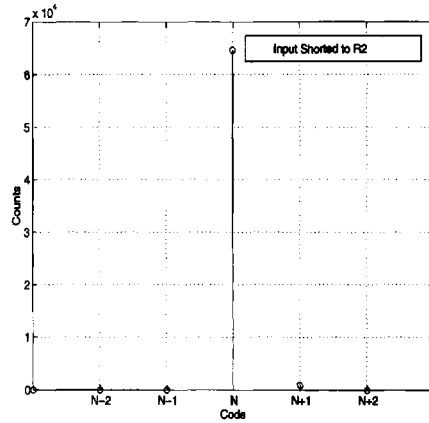


**Graph 5. Crossplot Staircase Output**  
 CLK = 6MSPS,  $V_{REF} = 4V$

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**Graph 6. XRD6406 Spectral Performance**



**Graph 7. XRD6406 Output Noise Histogram**